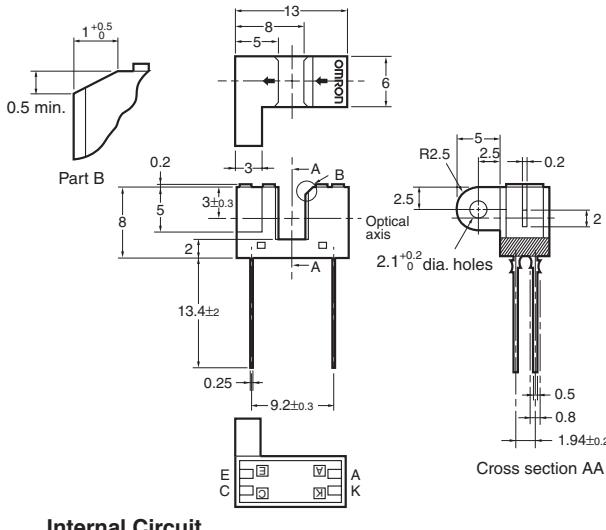


# Photomicrosensor (Transmissive) EE-SX129

**⚠ Be sure to read *Precautions* on page 25.**

## Dimensions

Note: All units are in millimeters unless otherwise indicated.



Unless otherwise specified, the tolerances are as shown below.

Dimensions	Tolerance
3 mm max.	±0.3
3 < mm ≤ 6	±0.375
6 < mm ≤ 10	±0.45
10 < mm ≤ 18	±0.55
18 < mm ≤ 30	±0.65

## Features

- High-resolution model with a 0.2-mm-wide sensing aperture.
- PCB mounting type.

## Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Item	Symbol	Rated value
Emitter	Forward current	$I_F$ 50 mA (see note 1)
	Pulse forward current	$I_{FP}$ 1 A (see note 2)
	Reverse voltage	$V_R$ 4 V
Detector	Collector-Emitter voltage	$V_{CEO}$ 30 V
	Emitter-Collector voltage	$V_{ECO}$ ---
	Collector current	$I_C$ 20 mA
	Collector dissipation	$P_c$ 100 mW (see note 1)
Ambient temperature	Operating	$T_{opr}$ -25°C to 85°C
	Storage	$T_{stg}$ -40°C to 100°C
Soldering temperature		$T_{sol}$ 260°C (see note 3)

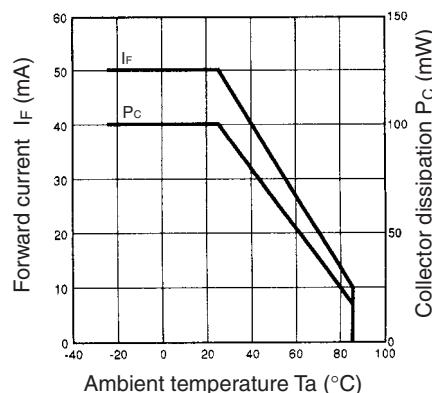
- Note:
- Refer to the temperature rating chart if the ambient temperature exceeds 25°C.
  - The pulse width is 10  $\mu\text{s}$  maximum with a frequency of 100 Hz.
  - Complete soldering within 10 seconds.

## Electrical and Optical Characteristics ( $T_a = 25^\circ\text{C}$ )

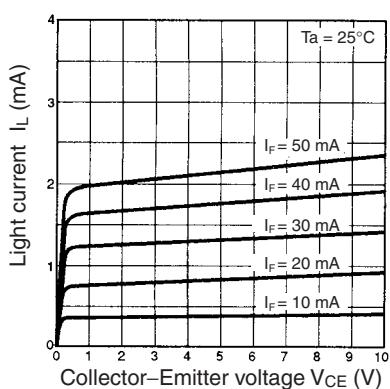
Item	Symbol	Value	Condition
Emitter	Forward voltage	$V_F$ 1.2 V typ., 1.5 V max.	$I_F = 30 \text{ mA}$
	Reverse current	$I_R$ 0.01 $\mu\text{A}$ typ., 10 $\mu\text{A}$ max.	$V_R = 4 \text{ V}$
	Peak emission wavelength	$\lambda_p$ 920 nm typ.	$I_F = 20 \text{ mA}$
Detector	Light current	$I_L$ 0.2 mA min.	$I_F = 20 \text{ mA}, V_{CE} = 10 \text{ V}$
	Dark current	$I_D$ 2 nA typ., 200 nA max.	$V_{CE} = 10 \text{ V}, 0 \text{ lux}$
	Leakage current	$I_{LEAK}$ ---	---
	Collector-Emitter saturated voltage	$V_{CE} (\text{sat})$ ---	---
	Peak spectral sensitivity wavelength	$\lambda_p$ 850 nm typ.	$V_{CE} = 10 \text{ V}$
Rising time	tr	4 $\mu\text{s}$ typ.	$V_{CC} = 5 \text{ V}, R_L = 100 \Omega, I_L = 5 \text{ mA}$
Falling time	tf	4 $\mu\text{s}$ typ.	$V_{CC} = 5 \text{ V}, R_L = 100 \Omega, I_L = 5 \text{ mA}$

## ■ Engineering Data

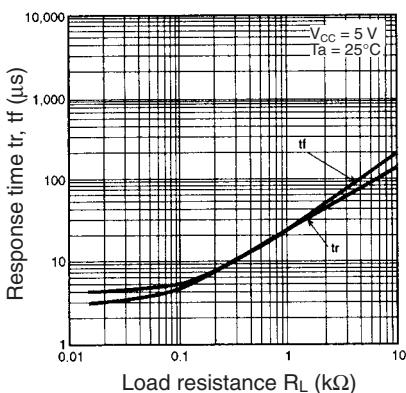
**Forward Current vs. Collector Dissipation Temperature Rating**



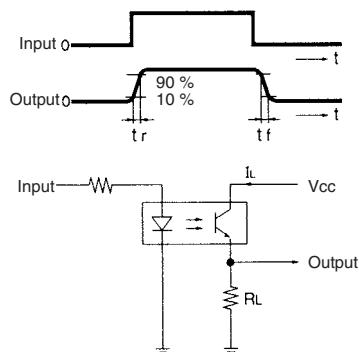
**Light Current vs. Collector-Emitter Voltage Characteristics (Typical)**



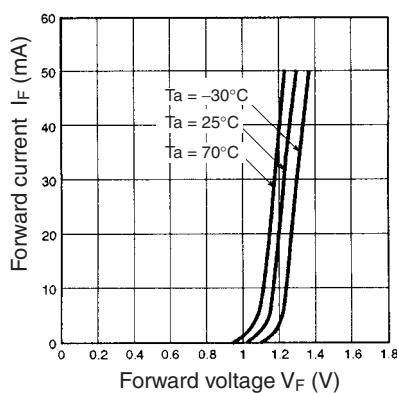
**Response Time vs. Load Resistance Characteristics (Typical)**



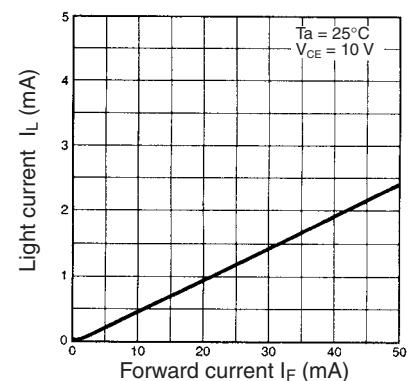
**Response Time Measurement Circuit**



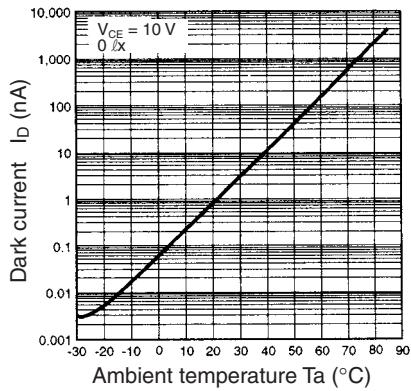
**Forward Current vs. Forward Voltage Characteristics (Typical)**



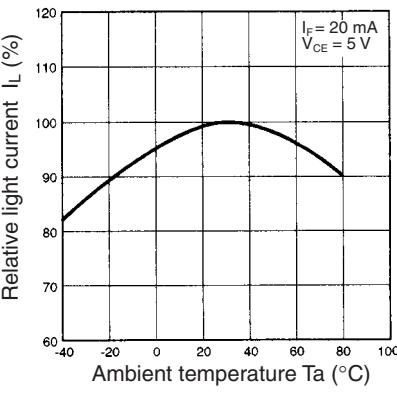
**Light Current vs. Forward Current Characteristics (Typical)**



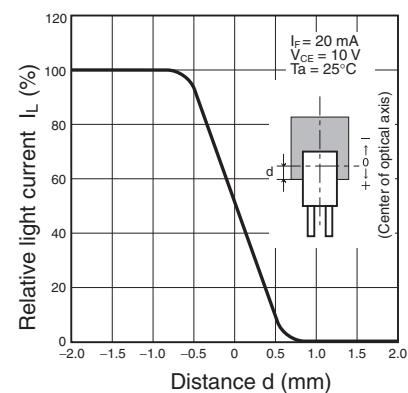
**Dark Current vs. Ambient Temperature Characteristics (Typical)**



**Relative Light Current vs. Ambient Temperature Characteristics (Typical)**



**Sensing Position Characteristics (Typical)**



**Sensing Position Characteristics (Typical)**



# X-ON Electronics

Largest Supplier of Electrical and Electronic Components

***Click to view similar products for Optical Switches, Transmissive, Phototransistor Output category:***

***Click to view products by Omron manufacturer:***

Other Similar products are found below :

[LTH-301-07](#) [LTH-301-23](#) [E3C-X2C](#) [E3S-LS20B4S1](#) [E3SX2CE4](#) [RPI-0125B](#) [RPI-2501](#) [RPI-576A](#) [KRA021](#) [LTH-306-04M](#) [LTH-309-08](#)  
[HOA0865-100](#) [HOA1961-055](#) [E3F-3C4](#) [LTH-306-01](#) [RPI-574](#) [EESX677C1JR01M](#) [SIT506F-A](#) [HOA1883-501](#) [PT928-6B-F](#) [RPI-243](#) [EE-SX675P-WR 1M](#) [OPB806](#) [EE-SX1128](#) [OPB857Z](#) [EE-SV3-B](#) [EE-SJ3-D](#) [RPI-0226](#) [EE-SX951P-W 1M](#) [EE-SX672R](#) [EE-SX670P-WR 1M](#)  
[LTH-301-32](#) [EESX674PWR1M](#) [EE-SX952-W 1M](#) [RPI-0352E](#) [RPI-352C40N](#) [DY-ITR002](#) [DY-ITR1100](#) [DY-ITR9909-W2](#) [HOA0825-001](#)  
[HOA0825-003](#) [HOA0860-N51](#) [HOA0861-N55](#) [HOA0861-P55](#) [HOA0861-T55](#) [HOA0866-P55](#) [HOA0866-T55](#) [HOA0867-P55](#) [HOA0867-T55](#) [HOA0870-T51](#)